2SC3979, 2SC3979A

Silicon NPN triple diffusion planar type

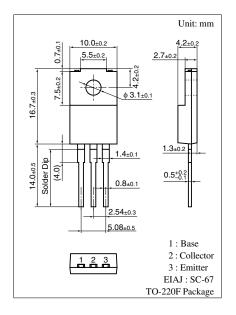
For high breakdown voltage high-speed switching

■ Features

- High-speed switching
- High collector to base voltage V_{CBO}
- Wide area of safe operation (ASO)
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

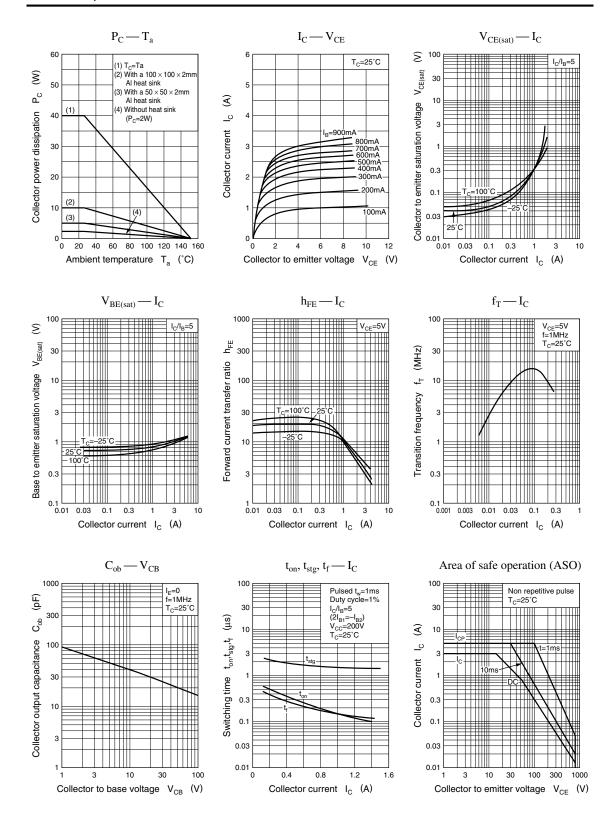
Parameter		Symbol	Rating	Unit		
Collector to base	2SC3979	V _{CBO}	900	V		
voltage	2SC3979A		1 000			
Collector to	2SC3979	V _{CES}	900	V		
emitter voltage	2SC3979A		1 000			
Collector to emitter voltage		V _{CEO}	800	V		
Emitter to base voltage		V _{EBO}	7	V		
Peak collector current		I_{CP}	5	A		
Collector current		I_{C}	3	A		
Base current		I_{B}	1	A		
Collector power	$T_C = 25^{\circ}C$	$P_{\rm C}$	40	W		
dissipation	$T_a = 25^{\circ}C$		2			
Junction temperature		T _j	150	°C		
Storage temperature		T_{stg}	-55 to +150	°C		



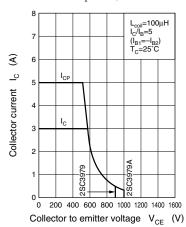
■ Electrical Characteristics $T_C = 25$ °C

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff	2SC3979	I_{CBO}	$V_{CB} = 900 \text{ V}, I_E = 0$			50	μА
current	2SC3979A		$V_{CB} = 1\ 000\ V, I_E = 0$			50	
Emitter cutoff current	•	I_{EBO}	$V_{EB} = 7 \text{ V}, I_{C} = 0$			50	μΑ
Collector to emitter vo	ltage	V _{CEO}	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	800			V
Forward current transfe	er ratio	h _{FE1}	$V_{CE} = 5 \text{ V}, I_{C} = 0.1 \text{ A}$	8			
		h _{FE2}	$V_{CE} = 5 \text{ V}, I_{C} = 0.8 \text{ A}$	6			
Collector to emitter satu	ration voltage	V _{CE(sat)}	$I_C = 0.8 \text{ A}, I_B = 0.16 \text{ A}$			1.5	V
Base to emitter saturati	on voltage	V _{BE(sat)}	$I_C = 0.8 \text{ A}, I_B = 0.16 \text{ A}$			1.5	V
Transition frequency		f_T	$V_{CE} = 5 \text{ V}, I_{C} = 0.15 \text{ A}, f = 1 \text{ MHz}$		10		MHz
Turn-on time		t _{on}	$I_C = 0.8 \text{ A}, I_{B1} = 0.16 \text{ A}, I_{B2} = -0.32 \text{ A},$			0.7	μs
Storage time		t _{stg}	$V_{CC} = 250 \text{ V}$			2.5	μs
Fall time		t _f				0.3	μs

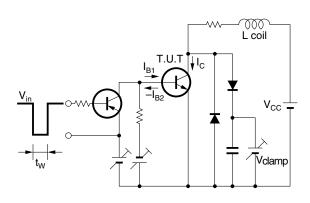
Panasonic 1

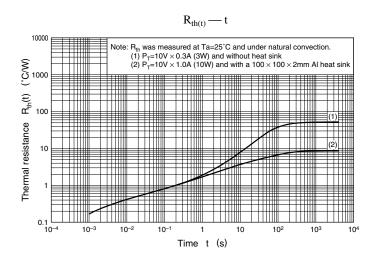


Area of safe operation, reverse bias ASO



Reverse bias ASO measuring circuit





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